

Continental Device India Limited

An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company



NPN SILICON PLANAR EPITAXIAL TRANSISTORS



MPSA44 MPSA45

TO-92 Plastic Package

High Voltage Transistors

Complementary of MPSA44 is MPSA94

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	MPSA44	MPSA45	UNITS
Collector Base Voltage	V_{CBO}	500	400	V
Collector Emitter Voltage	V _{CEO}	400	350	V
Emitter Base Voltage	V_{EBO}	6.	V	
Collector Current	I _C	30	mA	
Power Dissipation @ T _a =25°C	P_{D}	625		mW
Derate Above 25°C		5.0		mW/ºC
Power Dissipation @ T _c =25°C	P_{D}	1.5		W
Derate Above 25°C		12		mW/ºC
Operating And Storage Junction Temperature Range	T_{j},T_{stg}	- 55 to +150		°C

THERMAL CHARACTERISTICS

Junction to Case	R _{th (j-c)}	83.3	°C
Junction to Ambient in free air	R _{th (j-a)}	200	°C

ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNITS
Collector Emitter Voltage	V_{CEO}	I _C =1mA, I _B =0			
		MPSA44	400		V
		MPSA45	350		V
Collector Emitter Voltage	V_{CES}	$I_{C}=100\mu A, V_{BE}=0$			
		MPSA44	500		V
		MPSA45	400		V
Collector Base Voltage	V_{CBO}	$I_{C}=100\mu A, I_{E}=0$			
		MPSA44	500		V
		MPSA45	400		V
Emitter Base Voltage	V_{EBO}	$I_{E}=10\mu A, I_{C}=0$	6		V
Collector Cut Of Current	I _{CBO}	V _{CB} =400V, I _E =0, MPSA44		100	nA
		V_{CB} =320V, I_E =0, MPSA45		100	nA
Collector Cut Off Current	I _{CES}	V_{CE} =400V, V_{BE} = 0, MPSA44		500	nA
		$V_{CE} = 320V, V_{BE} = 0, MPSA45$		500	nA
Emitter Cut off Current	I _{EBO}	$V_{EB}=4V$, $I_C=0$		100	nA

NPN SILICON PLANAR EPITAXIAL TRANSISTORS



MPSA44 MPSA45

TO-92

Plastic Package

ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNITS
DC Current Gain	*h _{FE}	V_{CE} =10V, I_{C} =1mA	40		
		V_{CE} =10V, I_{C} =10mA	50	200	
		V_{CE} =10V, I_{C} =50mA	45		
		V_{CE} =10V, I_{C} =100mA	40		
Collector Emitter Saturation Voltage	*V _{CE (sat)}	$I_C=1mA$, $I_B=0.1mA$		0.40	V
		$I_C=10mA$, $I_B=1mA$		0.50	V
		$I_C=50$ mA, $I_B=5$ mA		0.75	V
Base Emitter Saturation Voltage	*V _{BE (sat)}	$I_C=10mA$, $I_B=1mA$		0.75	V

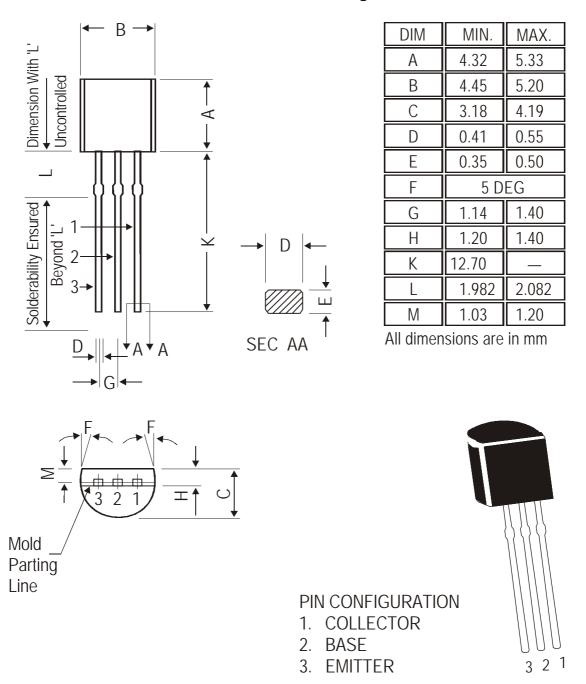
DYNAMIC CHARACTERISTICS

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNITS
Output Capacitance	C_{obo}	V_{CB} =20V, I_E =0, f=1MHz		7	pF
Input Capacitance	C_{ibo}	V_{EB} =0.5V, I_{C} =0, f=1MHz		130	pF
Small Signal Current Gain	h _{fe}	$I_C=10mA$, $V_{CE}=10V$, $f=10MHz$	2		

^{*}Pulse test: Pulse Width <300ms, Duty Cycle<2%

TO-92 Plastic Package

TO-92 Plastic Package



The TO-92 Package, Tape and Ammo Pack Drawings are correct as on the date of issue/revision of this Data Sheet.

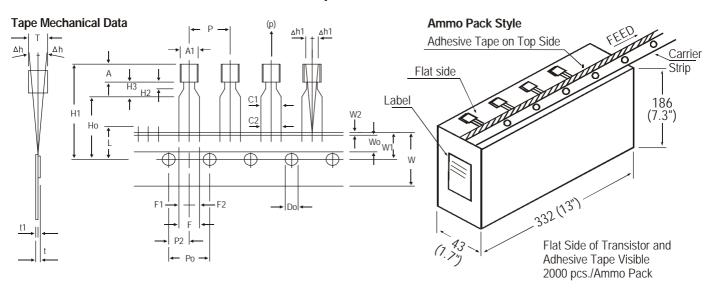
The currently valid dimensions and information, may please be confirmed from the TO-92 Drawing in the Packages and Packing Section of the Product Catalogue.

Packing Details

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Oty	Size	Qty	Size	Qty	Gr Wt
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	23 kgs
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	12.5 kgs

TO-92 Plastic Package

TO-92 Tape and Ammo Pack



All dimensions are in mm

		SPECIFICATION				
ITEM	SYMBOL	MIN.	NOM.	MAX.	TOL.	
BODY WIDTH	A1	4.0		4.8		NOTES
BODY HEIGHT	А	4.8		5.2		1. Maxim
BODY THICKNESS	Т	3.9		4.2		leads v
PITCH OF COMPONENT	Р		12.7		± 1.0	2. Maxim
*1FEED HOLE PITCH *2 FEED HOLE CENTRE TO	Ро		12.7		± 0.3	betwee exceed
COMPONENT CENTRE	P2		6.35		± 0.4	3. Holddo
DISTANCE BETWEEN OUTER LEADS	F		5.08		+ 0.6 - 0.2	the edo shall b
*3 COMPONENT ALIGNMENT SIDE VIEW	∆h		0	1.0		4. There
*4 COMPONENT ALIGNMENT FRONT VIEW	∆h1		0	1.3		consec
TAPE WIDTH	W		18		$\pm~0.5$	tape.
HOLD-DOWN TAPE WIDTH	Wo		6		± 0.2	5. A tape holes a
HOLE POSITION	W1		9		+ 0.7 - 0.5	compo
HOLD-DOWN TAPE POSITION	W2		0.5		± 0.2	6. Splices
LEAD WIRE CLINCH HEIGHT	Но		16		± 0.5	sprock
COMPONENT HEIGHT	H1			23.25		
LENGTH OF SNIPPED LEADS	L			11.0		
FEED HOLE DIAMETER	Do		4		± 0.2	REMARK
*5 TOTAL TAPE THICKNESS	t			1.2		*1 Cumul
LEAD - TO - LEAD DISTANCE	F1, F2		2.54		+ 0.4 - 0.1	*2 To be i
STAND OFF	H2	0.45		1.45	- 0.1	
CLINCH HEIGHT	H3			3.0		*3 At top
LEAD PARALLELISM	C1 - C2			0.22		*4 At top
PULL - OUT FORCE	(p)	6N				*5 t1 0.3

- num alignment deviation between will not to be greater than 0.2mm.
- num non-cumulative variation en tape feed holes shall not ed 1 mm in 20 pitches.
- own tape will not exceed beyond dge(s) of carrier tape and there be no exposure of adhesive.
- will be no more than three (3) ecutive missing components in a
- e trailer, having at least three feed are provided after the last onent in a tape.
- es should not interfere with the ket feed holes.

KS

- lative pitch error 1.0 mm/20 pitch
- measured at bottom of clinch
- of body
- of body
- 3 0.6 mm

Notes MPSA44 MPSA45

TO-92 Plastic Package

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



CDIL is a registered Trademark of
Continental Device India Limited
C-120 Naraina Industrial Area, New Delhi 110 028, India.
Telephone + 91-11-2579 6150, 5141 1112 Fax + 91-11-2579 5290, 5141 1119
email@cdil.com www.cdilsemi.com